SKB 2



Miniature Bridge Rectifiers

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Features

- Compact plastic package with in-line terminals
- High blocking voltage

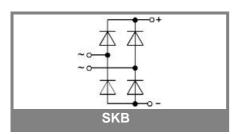
Typical Applications

- Internal power supplies for electronic equipment
- DC power supplies
- Control equipment
- TV sets
- Recommended snubber network: RC: 10 nF, 20...50 Ω (P _R = 1 W)

1) Freely suspended or mounted on an insulator

Mounted on a painted metal sheet of min.
250 x 250 x 1 mm

$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	V _{RSM} , V _{RRM}	M V _{VRMS}	I _D = 2,5 A (T _a = 45	°C) C	max	R _{min}
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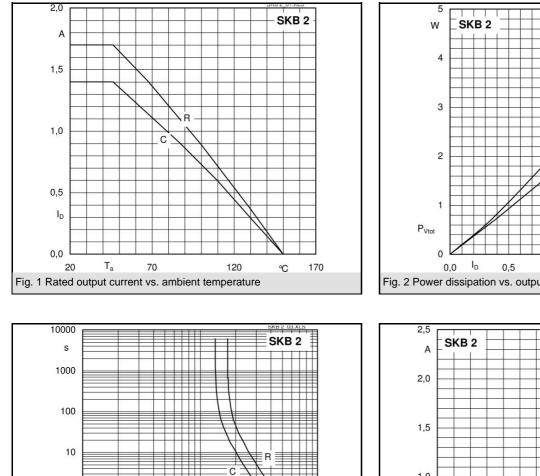
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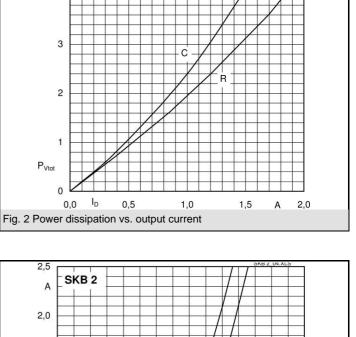
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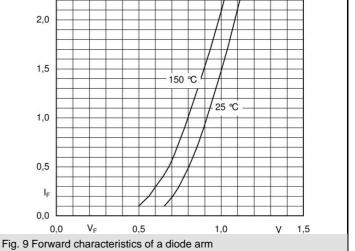
Fig. 6 Rated overload characteristics vs. time

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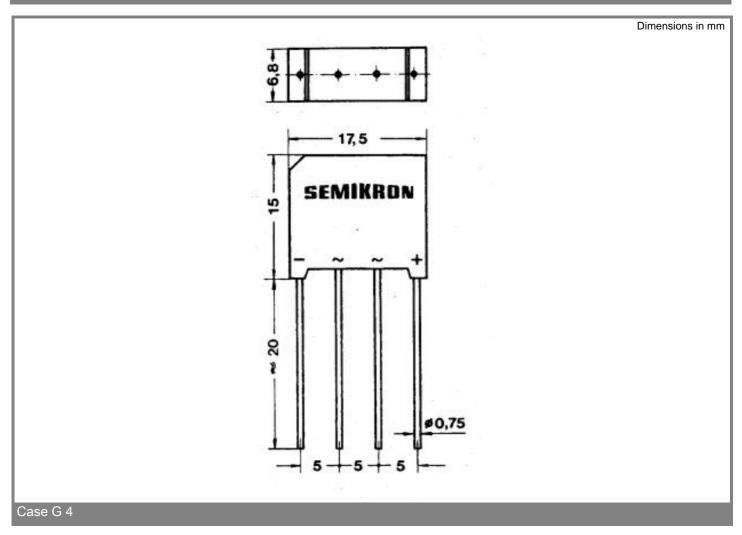




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